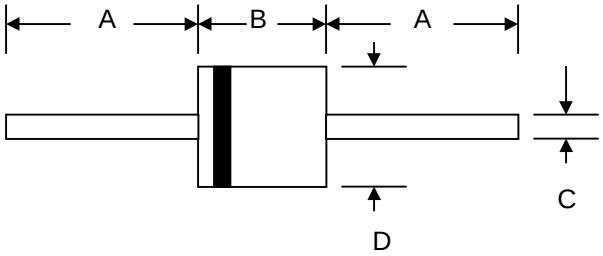
10A05 – 10A10

10A Axial Leaded Standard Diode

Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability



R-6		
Dim	**Min**	**Max**
A	25.4	—
B	8.60	9.10
C	1.20	1.30
D	8.60	9.10
All Dimensions in mm		

Mechanical Data

- Case: P-600, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 2.1 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version, Add "-LF" Suffix to Part Number, See Page 4**

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
For capacitive load, derate current by 20%.

Characteristic	Symbol	10A05	10A1	10A2	10A4	10A6	10A8	10A10	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @T_A = 50°C	I_O	10							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	600							A
Forward Voltage @I_F = 10A	V_{FM}	1.0							V
Peak Reverse Current @T_A = 25°C At Rated DC Blocking Voltage @T_A = 100°C	I_{RM}	10 100							μA
Typical Junction Capacitance (Note 2)	C_j	150				80			pF
Typical Thermal Resistance Junction to Ambient (Note 1)	$R_{\theta JA}$	10							°C/W
Operating Temperature Range	T_j	-50 to +150							°C
Storage Temperature Range	T_{STG}	-50 to +150							°C

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

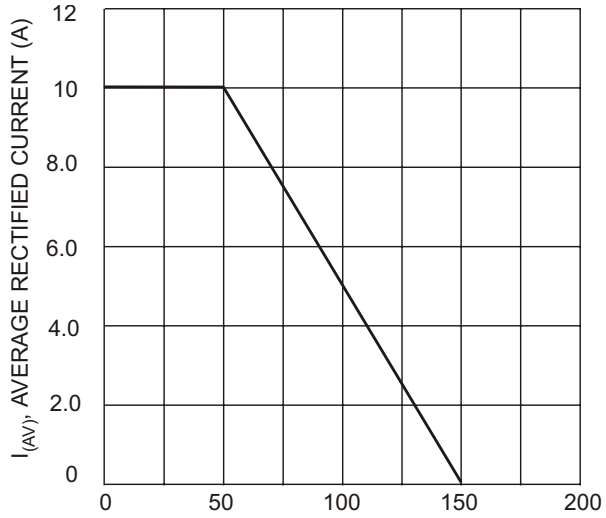


Fig. 1 Forward Current Derating Curve

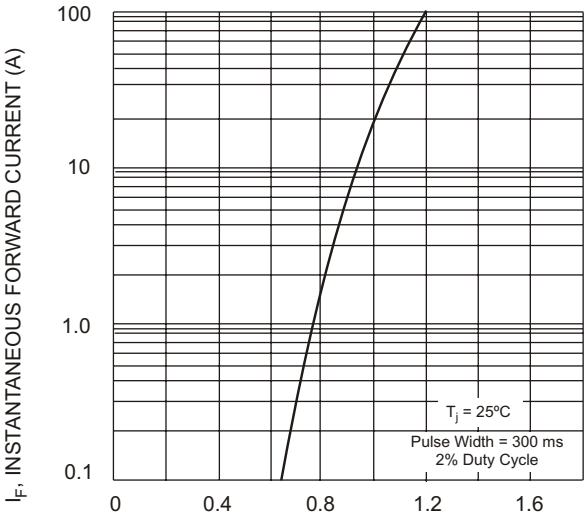


Fig. 2 Typical Forward Characteristics

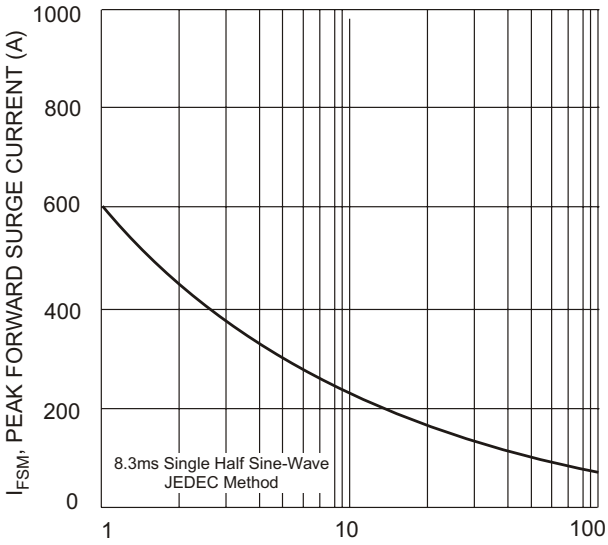


Fig. 3 Maximum Non-Repetitive Peak Forward Surge Current

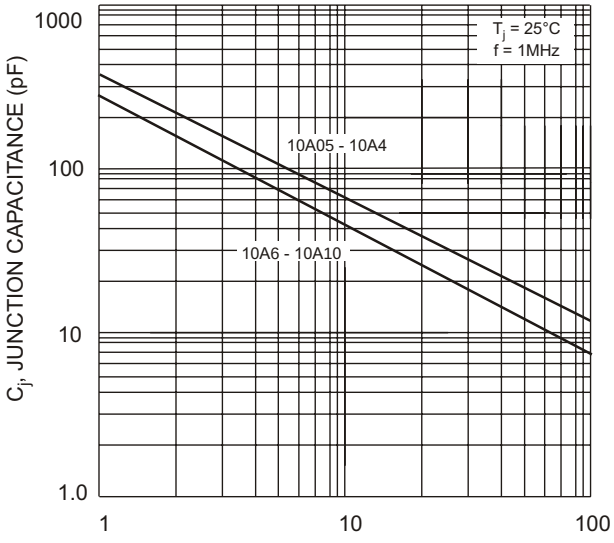


Fig. 4 Typical Junction Capacitance